

# 4.5V Drive Nch MOSFET

## RMW150N03

#### Structure

Silicon N-channel MOSFET

## Features

- 1) High Power package(PSOP8).
- 2) High-speed switching,Low On-resistance.
- 3) Low voltage drive(4.5V drive).

## Application

Switching

Packaging specifications

Туре	Package	Taping				
	Code	TB				
	Basic ordering unit (pieces)	2500				
RMW150N03		0				

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		$V_{DSS}$	30	V
Gate-source voltage		$V_{GSS}$	<u>+20</u>	V
Drain current	Continuous	$I_D$	±15	Α
	Pulsed	I <sub>DP</sub> *1	±60	Α
Source current	Continuous	I <sub>S</sub>	2.5	Α
(Body Diode)	Pulsed	I <sub>SP</sub> *1	60	Α
Power dissipation		P <sub>D</sub> *2	3.0	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

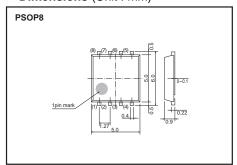
<sup>\*1</sup> Pw≤10µs, Duty cycle≤1%

## ● Thermal resistance

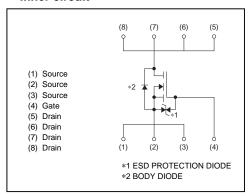
Parameter	Symbol	Limits	Unit
Channel to Ambient	Rth (ch-a)*	41.7	°C/W

<sup>\*2</sup> MOUNTED ON 40mm × 40mm Cu BOARD

#### • Dimensions (Unit : mm)



## • Inner circuit



<sup>\*2</sup> MOUNTED ON 40mm × 40mm Cu BOARD

## ● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	±10	μA	$V_{GS}=\pm20V$ , $V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	30	-	-	٧	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	•	-	1	μA	$V_{DS}$ =30V, $V_{GS}$ =0V
Gate threshold voltage	V <sub>GS (th)</sub>	1.0	-	2.5	٧	$V_{DS}$ =10V, $I_{D}$ =1mA
Static drain-source on-state	R <sub>DS (on)</sub> *	•	6.5	9.1	mΩ	I <sub>D</sub> =15A, V <sub>GS</sub> =10V
resistance	DS (on)	•	9.0	12.6		I <sub>D</sub> =15A, V <sub>GS</sub> =4.5V
Forward transfer admittance	IY <sub>fs</sub> f*	10	-	-	S	I <sub>D</sub> =15A, V <sub>DS</sub> =10V
Input capacitance	C <sub>iss</sub>	1	831	-	pF	V <sub>DS</sub> =15V
Output capacitance	C <sub>oss</sub>	1	337	-	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	1	95	-	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	1	12	-	ns	I <sub>D</sub> =7.5A, V <sub>DD</sub> ≒ 15V
Rise time	t <sub>r</sub> *	•	38	-	ns	V <sub>GS</sub> =10V
Turn-off delay time	t <sub>d(off)</sub> *	1	34	-	ns	$R_L=2.0\Omega$
Fall time	t <sub>f</sub> *	ı	9	-	ns	$R_G=10\Omega$
Total gate charge	Q <sub>g</sub> *	•	15	-	nC	I <sub>D</sub> =15A, V <sub>DD</sub> ≒15V
Gate-source charge	Q <sub>gs</sub> *	-	2.6	-	nC	V <sub>GS</sub> =10V
Gate-drain charge	Q <sub>gd</sub> *	-	3.0	-	nC	

<sup>\*</sup>Pulsed

## ●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward Voltage	V <sub>SD</sub> *	-	-	1.2	V	$I_s$ =2.5A, $V_{GS}$ =0V

<sup>\*</sup>Pulsed

## ●Electrical characteristic curves (Ta=25°C)

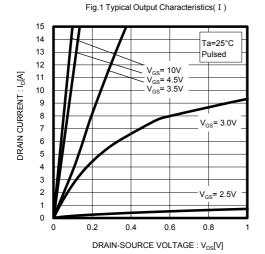
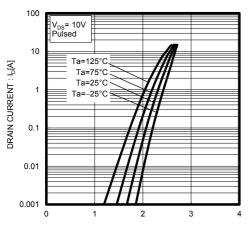


Fig.3 Typical Transfer Characteristics



GATE-SOURCE VOLTAGE :  $V_{GS}[V]$ 

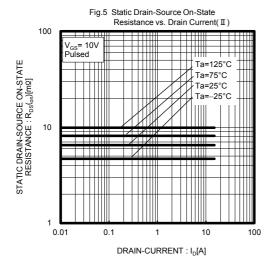


Fig.2 Typical Output Characteristics( II )

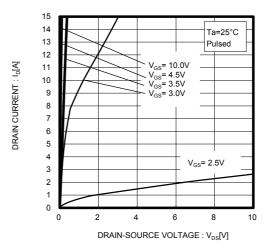
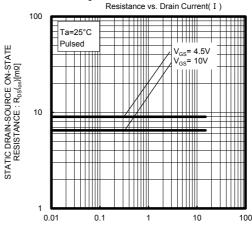
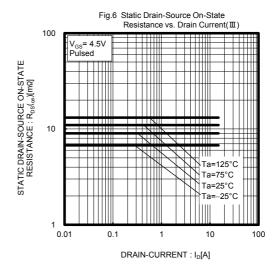
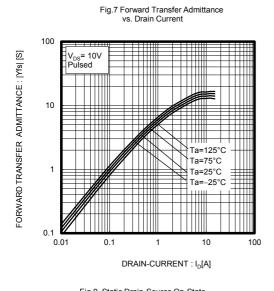


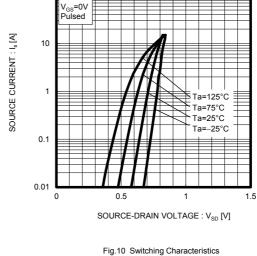
Fig.4 Static Drain-Source On-State



 $\mathsf{DRAIN}\text{-}\mathsf{CURRENT}:\mathsf{I}_\mathsf{D}[\mathsf{A}]$ 

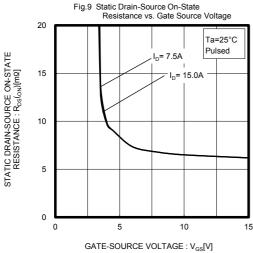


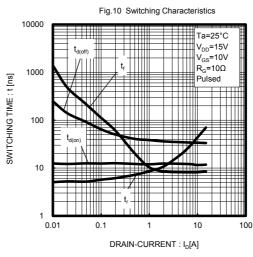


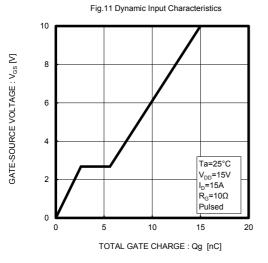


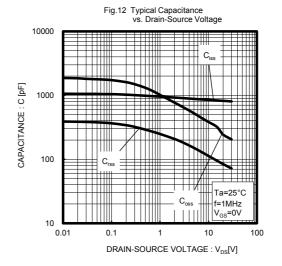
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Fig.8 Reverse Drain Current vs. Sourse-Drain Voltage









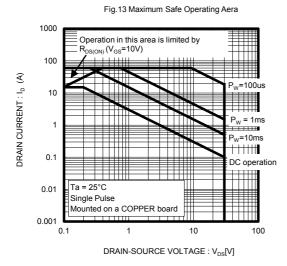
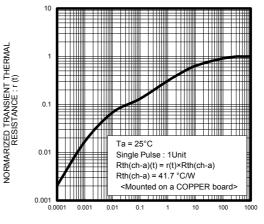


Fig.14 Normalized Transient Thermal Resistance vs. Pulse Width



PULSE WIDTH : Pw(s)

## Measurement circuits

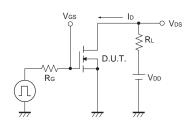


Fig.1-1 Switching Time Measurement Circuit

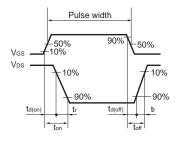
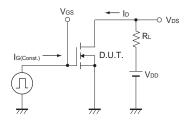


Fig.1-2 Switching Waveforms





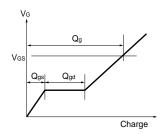


Fig.2-2 Gate Charge Waveform

## Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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